

74LVCH32245A

32-bit bus transceiver with direction pin; 5 V tolerant; 3-state

Rev. 03 — 20 August 2007

Product data sheet

1. General description

The 74LVCH32245A is a 32-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The device features four output enable ($\overline{\text{nOE}}$) inputs for easy cascading and four send/receive ($\overline{\text{nDIR}}$) inputs for direction control. Pin $\overline{\text{nOE}}$ controls the outputs so that the buses are effectively isolated.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices in mixed 3.3 V and 5 V applications.

To ensure the high-impedance state during power-up or power-down, pin $\overline{\text{nOE}}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

2. Features

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- MULTIBYTE flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- High-impedance when $V_{\text{CC}} = 0$ V
- All data inputs have bus hold
- Complies with JEDEC standard JESD8-B / JESD36
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Specified from -40 °C to $+85$ °C
- Packaged in plastic fine-pitch ball grid array package

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|----------------|-------------------|---------|---|----------|
| | Temperature range | Name | Description | Version |
| 74LVCH32245AEC | −40 °C to +85 °C | LFBGA96 | plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 × 5.5 × 1.05 mm | SOT536-1 |

4. Functional diagram

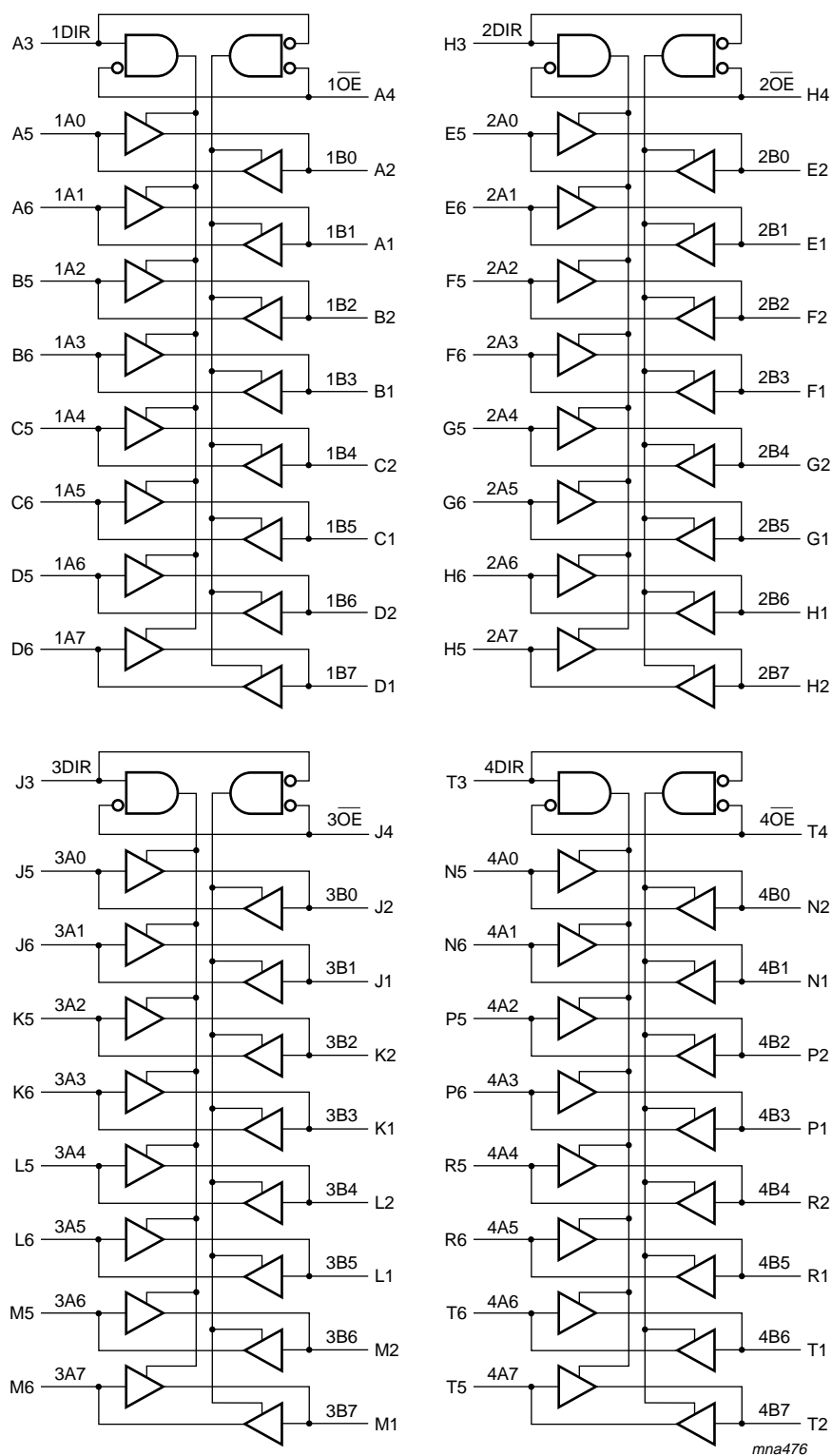


Fig 1. Logic symbol

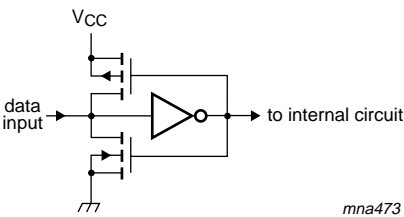


Fig 2. Bus hold circuit

5. Pinning information

5.1 Pinning

mna475

| | | | | | | | | | | | | | | | | |
|---|------|-----|-----|-----|-----|-----|-----|------|------|-----|-----|-----|-----|-----|-----|------|
| 6 | 1A1 | 1A3 | 1A5 | 1A7 | 2A1 | 2A3 | 2A5 | 2A6 | 3A1 | 3A3 | 3A5 | 3A7 | 4A1 | 4A3 | 4A5 | 4A6 |
| 5 | 1A0 | 1A2 | 1A4 | 1A6 | 2A0 | 2A2 | 2A4 | 2A7 | 3A0 | 3A2 | 3A4 | 3A6 | 4A0 | 4A2 | 4A4 | 4A7 |
| 4 | 1OE | GND | VCC | GND | GND | VCC | GND | 2OE | 3OE | GND | VCC | GND | GND | VCC | GND | 4OE |
| 3 | 1DIR | GND | VCC | GND | GND | VCC | GND | 2DIR | 3DIR | GND | VCC | GND | GND | VCC | GND | 4DIR |
| 2 | 1B0 | 1B2 | 1B4 | 1B6 | 2B0 | 2B2 | 2B4 | 2B7 | 3B0 | 3B2 | 3B4 | 3B6 | 4B0 | 4B2 | 4B4 | 4B7 |
| 1 | 1B1 | 1B3 | 1B5 | 1B7 | 2B1 | 2B3 | 2B5 | 2B6 | 3B1 | 3B3 | 3B5 | 3B7 | 4B1 | 4B3 | 4B5 | 4B6 |
| | A | B | C | D | E | F | G | H | J | K | L | M | N | P | R | T |

Fig 3. Pin configuration

5.2 Pin description

Table 2. Pin description

| Pin name | Ball | Description |
|-------------------|--|----------------------------------|
| nDIR (n = 1 to 4) | A3, H3, J3, T3 | direction control |
| nOE (n = 1 to 4) | A4, H4, J4, T4 | output enable input (active LOW) |
| 1A[0:7] | A5, A6, B5, B6, C5, C6, D5, D6 | input or output |
| 1B[0:7] | A2, A1, B2, B1, C2, C1, D2, D1 | input or output |
| 2A[0:7] | E5, E6, F5, F6, G5, G6, H6, H5 | input or output |
| 2B[0:7] | E2, E1, F2, F1, G2, G1, H1, H2 | input or output |
| 3A[0:7] | J5, J6, K5, K6, L5, L6, M5, M6 | input or output |
| 3B[0:7] | J2, J1, K2, K1, L2, L1, M2, M1 | input or output |
| 4A[0:7] | N5, N6, P5, P6, R5, R6, T6, T5 | input or output |
| 4B[0:7] | N2, N1, P2, P1, R2, R1, T1, T2 | input or output |
| GND | B3, B4, D3, D4, E3, E4, G3, G4, K3, K4, M3, M4, N3, N4, R3, R4 | ground (0 V) |
| VCC | C3, C4, F3, F4, L3, L4, P3, P4 | supply voltage |

6. Functional description

Table 3. Function selection^[1]

| Input | | Output | |
|-------|------|--------|--------|
| nOE | nDIR | nAn | nBn |
| L | L | A = B | inputs |
| L | H | inputs | B = A |
| H | X | Z | Z |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|---------------------|-----------------------|------|
| V _{CC} | supply voltage | | -0.5 | +6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| V _I | input voltage | | ^[1] -0.5 | +6.5 | V |
| I _{OK} | output clamping current | V _O > V _{CC} or V _O < 0 V | - | ±50 | mA |
| V _O | output voltage | output HIGH or LOW state | ^[2] -0.5 | V _{CC} + 0.5 | V |
| | | output 3-state | ^[2] -0.5 | +6.5 | V |
| I _O | output current | V _O = 0 V to V _{CC} | - | ±50 | mA |
| I _{CC} | supply current | | ^[3] - | 200 | mA |
| I _{GND} | ground current | | ^[3] -200 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +85 °C | ^[4] - | 1000 | mW |

[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

[2] The output voltage ratings may be exceeded if the output current ratings are observed.

[3] All supply and ground pins connected externally to one voltage source.

[4] Above 70 °C the value of P_{tot} derates linearly with 1.8 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|-------------------------------------|----------------------------------|-----|-----|-----------------|------|
| V _{CC} | supply voltage | for maximum speed performance | 2.7 | - | 3.6 | V |
| | | for low-voltage applications | 1.2 | - | - | V |
| V _I | input voltage | | 0 | - | 5.5 | V |
| V _O | output voltage | output HIGH or LOW state | 0 | - | V _{CC} | V |
| | | output 3-state | 0 | - | 5.5 | V |
| T _{amb} | ambient temperature | in free air | -40 | - | +85 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 1.2 V to 2.7 V | - | - | 20 | ns/V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 10 | ns/V |

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | V _{CC} (V) | Min | Typ ^[1] | Max | Unit |
|---|---------------------------------|--|---------------------|-----------------------|--------------------|------|-------|
| T_{amb} = -40 °C to +85 °C | | | | | | | |
| V _{IH} | HIGH-level input voltage | | 1.2 | V _{CC} | - | - | V |
| | | | 2.7 to 3.6 | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | | 1.2 | - | - | GND | V |
| | | | 2.7 to 3.6 | - | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = -100 µA | 2.7 to 3.6 | V _{CC} - 0.2 | V _{CC} | - | V |
| | | I _O = -12 mA | 2.7 | V _{CC} - 0.5 | - | - | V |
| | | I _O = -18 mA | 3.0 | V _{CC} - 0.6 | - | - | V |
| | | I _O = -24 mA | 3.0 | V _{CC} - 0.8 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = 100 µA | 2.7 to 3.6 | - | GND | 0.20 | V |
| | | I _O = 12 mA | 2.7 | - | - | 0.40 | V |
| | | I _O = 24 mA | 3.0 | - | - | 0.55 | V |
| I _I | input leakage current | V _I = 5.5 V or GND | 3.6 | ^[2] | - | ±0.1 | ±5 µA |
| I _{OZ} | OFF-state output current | V _I = V _{IH} or V _{IL} ; V _O = 5.5 V or GND | 3.6 | ^{[2][3]} | - | ±0.1 | ±5 µA |
| I _{OFF} | power-off leakage current | V _I or V _O = 5.5 V | 0.0 | - | ±0.1 | ±10 | µA |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A | 3.6 | - | 0.1 | 40 | µA |
| ΔI _{CC} | additional supply current | per input pin; V _I = V _{CC} - 0.6 V; I _O = 0 A | 2.7 to 3.6 | - | 5 | 500 | µA |
| C _I | input capacitance | V _I = GND to V _{CC} | 0 to 3.6 | - | 5.0 | - | pF |
| C _{I/O} | input/output capacitance | V _I = GND to V _{CC} | 0 to 3.6 | - | 10 | - | pF |
| I _{BHL} | bus hold LOW current | V _I = 0.8 V | 3.0 | ^{[4][5]} | 75 | - | µA |
| I _{BHH} | bus hold HIGH current | V _I = 2.0 V | 3.0 | ^{[4][5]} | -75 | - | µA |
| I _{BHLO} | bus hold LOW overdrive current | | 3.6 | ^{[4][6]} | 500 | - | µA |
| I _{BHHO} | bus hold HIGH overdrive current | | 3.6 | ^{[4][6]} | -500 | - | µA |

[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

[2] The bus hold circuit is switched off when V_I > V_{CC} allowing 5.5 V on the input terminal.

[3] For I/O ports the parameter I_{OZ} includes the input leakage current.

[4] Valid for data inputs only. Note that control inputs do not have a bus hold circuit.

[5] The specified sustaining current at the data input holds the input below the specified V_I level.

[6] The specified overdrive current at the data input forces the data input to the opposite input state.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 6](#).

| Symbol | Parameter | Conditions | V _{CC} (V) | Min | Typ ^[1] | Max | Unit |
|---|-------------------------------|--|---------------------|---------------------|--------------------|------|--------|
| T_{amb} = -40 °C to +85 °C | | | | | | | |
| t _{pd} | propagation delay | nAn to nBn; nBn to nAn; see Figure 4 | 1.2 | [2] | - | 13.0 | - ns |
| | | | 2.7 | | 1.0 | 2.7 | 4.7 ns |
| | | | 3.0 to 3.6 | | 1.0 | 2.2 | 4.5 ns |
| t _{en} | enable time | n $\overline{\text{OE}}$ to nAn, nBn; see Figure 5 | 1.2 | [2] | - | 15.0 | - ns |
| | | | 2.7 | | 1.5 | 3.6 | 6.7 ns |
| | | | 3.0 to 3.6 | | 1.0 | 2.8 | 5.5 ns |
| t _{dis} | disable time | n $\overline{\text{OE}}$ to nAn, nBn; see Figure 5 | 1.2 | [2] | - | 11.0 | - ns |
| | | | 2.7 | | 1.5 | 3.4 | 6.6 ns |
| | | | 3.0 to 3.6 | | 1.5 | 3.2 | 5.6 ns |
| t _{sk(o)} | output skew time | | 3.0 to 3.6 | [3] | - | - | 1.0 ns |
| C _{PD} | power dissipation capacitance | per buffer; V _I = GND to V _{CC} | 3.3 | [4] | - | 30 | - pF |

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 2.7 V, and 3.3 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

t_{en} is the same as t_{PZL} and t_{PZH}.

t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; f_o = output frequency in MHz

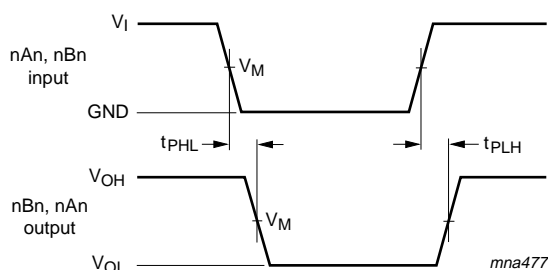
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms

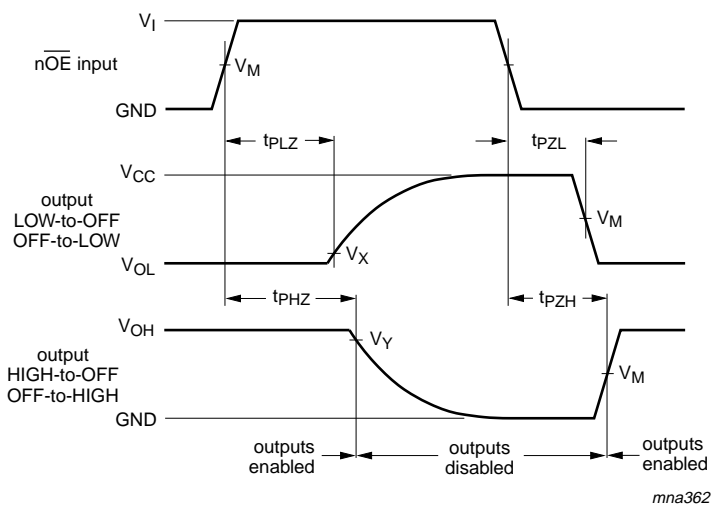


V_M = 1.5 V at V_{CC} ≥ 2.7 V.

V_M = 0.5 × V_{CC} at V_{CC} < 2.7 V.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. The input (nAn, nBn) to output (nBn, nAn) propagation delays



$V_M = 1.5 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$.

$V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7 \text{ V}$.

$V_X = V_{OL} + 0.3 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$;

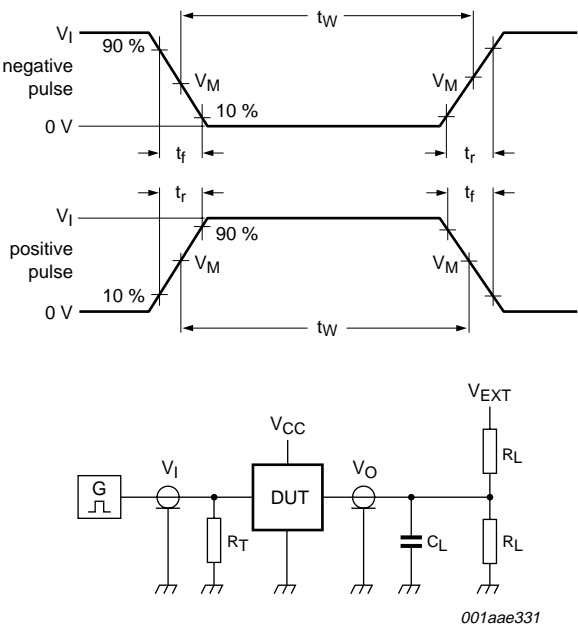
$V_X = V_{OL} + 0.15 \text{ V}$ at $V_{CC} < 2.7 \text{ V}$.

$V_Y = V_{OH} - 0.3 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$;

$V_Y = V_{OH} - 0.15 \text{ V}$ at $V_{CC} < 2.7 \text{ V}$.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 5. 3-state enable and disable times.



Test data is given in [Table 8](#).
Definitions for test circuit:
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.
 V_{EXT} = External voltage for measuring switching times.

Fig. 6. Load circuitry for switching times

Table 8. Test data

| Supply voltage | Input | | Load | | V_{EXT} | | |
|----------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| | V_I | t_r, t_f | C_L | R_L | t_{PLH}, t_{PHL} | t_{PLZ}, t_{PZL} | t_{PHZ}, t_{PZH} |
| 1.2 V | V_{CC} | ≤ 2 ns | 50 pF | 500 Ω | open | $2 \times V_{CC}$ | GND |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | $2 \times V_{CC}$ | GND |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | $2 \times V_{CC}$ | GND |

12. Package outline

LFBGA96: plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 x 5.5 x 1.05 mm SOT536-1

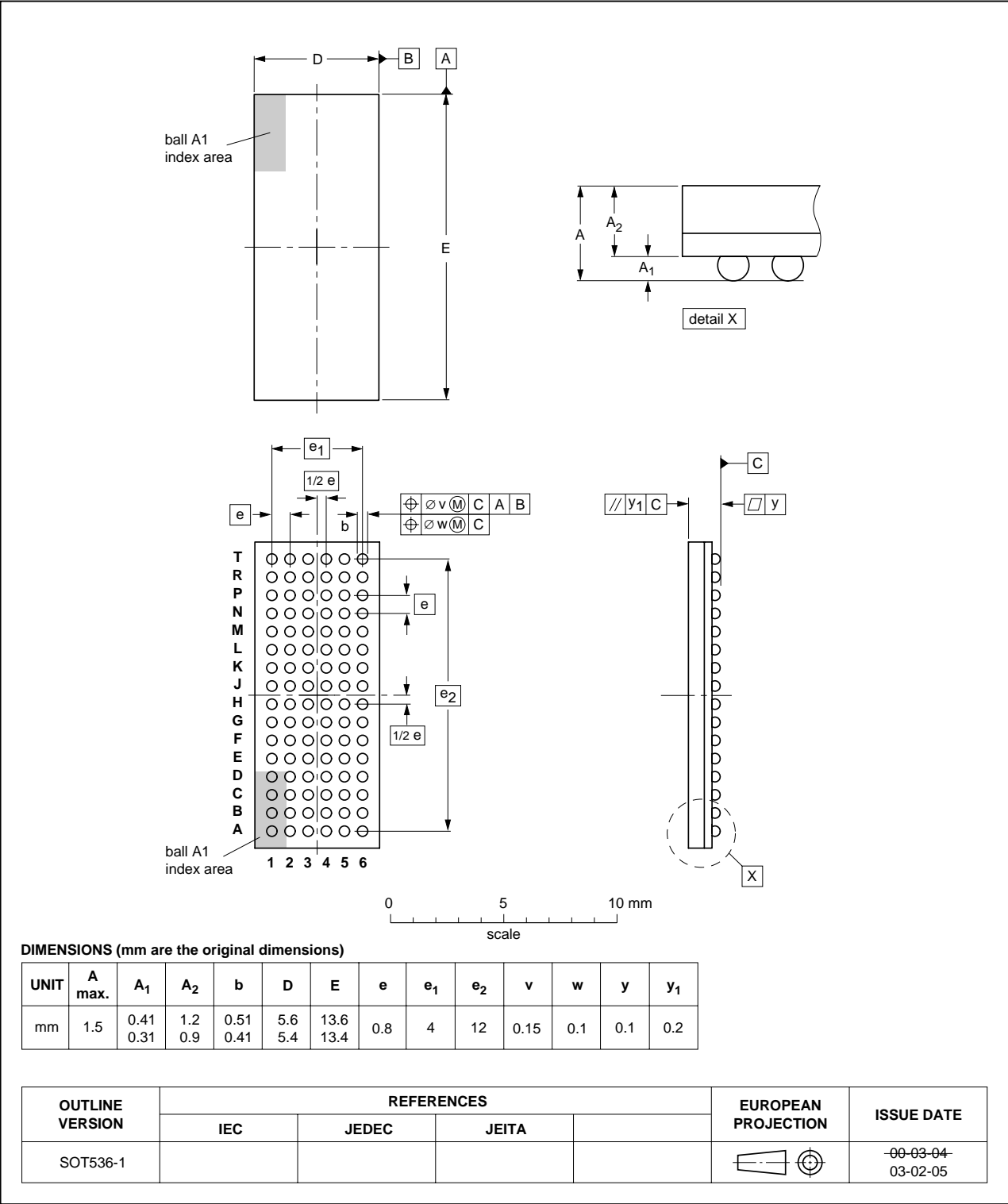


Fig 7. Package outline SOT536-1 (LFBGA96)

13. Abbreviations

Table 9. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---|--------------|-----------------------|---------------|--------------------|
| 74LVCH32245A_3 | 20070820 | Product data sheet | - | 74LVCH32245A_2 |
| Modifications: | | | | |
| <ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Error in Table 2 "Pin description" corrected.• Quick Reference Data section deleted. Information (C_{PD}, C_I, $C_{I/O}$) moved from it to Table 6 and Table 7.• Some parameter symbols and descriptions have been updated to comply with NXP guidelines. | | | | |
| 74LVCH32245A_2 | 20040511 | Product specification | - | 74LVC_LVCH32245A_1 |
| 74LVC_LVCH32245A_1 | 19990901 | - | - | - |

15. Legal information

15.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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17. Contents

| | | |
|-----------|---|-----------|
| 1 | General description | 1 |
| 2 | Features | 1 |
| 3 | Ordering information | 2 |
| 4 | Functional diagram | 3 |
| 5 | Pinning information | 4 |
| 5.1 | Pinning | 4 |
| 5.2 | Pin description | 4 |
| 6 | Functional description | 5 |
| 7 | Limiting values | 5 |
| 8 | Recommended operating conditions | 5 |
| 9 | Static characteristics | 6 |
| 10 | Dynamic characteristics | 7 |
| 11 | Waveforms | 7 |
| 12 | Package outline | 10 |
| 13 | Abbreviations | 11 |
| 14 | Revision history | 11 |
| 15 | Legal information | 12 |
| 15.1 | Data sheet status | 12 |
| 15.2 | Definitions | 12 |
| 15.3 | Disclaimers | 12 |
| 15.4 | Trademarks | 12 |
| 16 | Contact information | 12 |
| 17 | Contents | 13 |

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